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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC14P,TC74AC14F,TC74AC14FN,TC74AC14FT

Hex Schmitt Inverter

The TC74AC14 is an advanced high speed CMOS SCHMITT INVERTER fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low pwer dissipation.

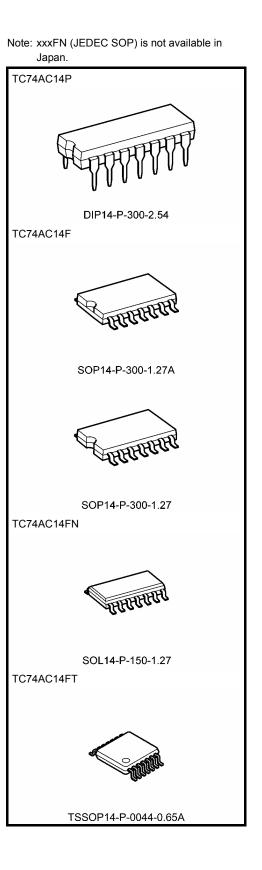
Pin configuration and function are the same as the TC74AC04 but the inputs have hysteresis and with its schmitt trigger function, the TC74AC14 can be used as a line receivers which will receive slow input signals.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

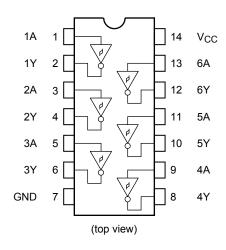
- High speed: $t_{pd} = 5.3 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \ \mu A \ (max)$ at $Ta = 25^{\circ}C$
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Pin and function compatible with 74F14

Weight	
DIP14-P-300-2.54	: 0.96 g (typ.)
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)



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Pin Assignment



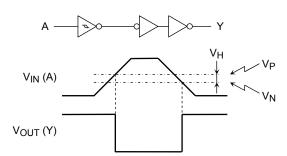
IEC Logic Symbol

1A	Д	(<u>2)</u> 1Y
2A <u>(3)</u>		(4) 2Y
3A <u>(5)</u>		(6) 3Y
4A <u>(9)</u>		(8) 4Y
5A (11)		(10) 5Y
6A (13)		(12) 6Y

Truth Table

А	Y
L	Н
Н	L

System Diagram, Waveform



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	IIК	±20	mA
Output diode current	lok	±50	mA
DC output current	IOUT	±50	mA
DC V _{CC} /ground current	ICC	±150	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 5.5	V
Input voltage	VIN	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC} (V)	Min	Тур.	Max	Min	Max	Onit	
					3.0	_	_	2.2	_	2.2		
Positive threshold voltage	VP		—		4.5	—	—	3.2	—	3.2	V	
					5.5	—	_	3.9	_	3.9		
					3.0	0.5	—	_	0.5	—		
Negative threshold voltage	V _N		_		4.5	0.9	—	_	0.9	—	V	
					5.5	1.1	_	_	1.1	_		
					3.0	0.3	—	1.2	0.3	1.2		
Hysteresis voltage	V _H		—		4.5	0.4	—	1.4	0.4	1.4	V	
					5.5	0.5	-	1.6	0.5	1.6		
	V _{OH}				2.0	1.9	2.0	—	1.9	—		
		V _{IN} = V _{IL}	I _{OH} = -50 μA		3.0	2.9	3.0	_	2.9	—		
High-level output					4.5	4.4	4.5	_	4.4	_	V	
voltage			I _{OH} = −4 mA		3.0	2.58	—	—	2.48	—	v	
			I _{OH} = −24 mA		4.5	3.94	—	—	3.80	—		
			I _{OH} = −75 mA	(Note)	5.5	—	-		3.85	-		
						2.0	—	0.0	0.1		0.1	
		V _{IN} = V _{IH}	I _{OL} = 50 μA		3.0	—	0.0	0.1	—	0.1		
Low-level output voltage	V _{OL}				4.5	_	0.0	0.1		0.1	- V	
	VOL		I _{OL} = 12 mA		3.0	—	—	0.36	—	0.44		
			I _{OL} = 24 mA		4.5	_	—	0.36	—	0.44		
			I _{OL} = 75 mA	(Note)	5.5	—	-		-	1.65		
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND			5.5	_		±0.1		±1.0	μA	
Quiescent supply current	ICC	V _{IN} = V _{CC} or GND			5.5	_	_	4.0	_	40.0	μA	

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Symbol		Ta = 25°C		Ta −40 to	Unit		
	,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t _{pLH}		3.3 ± 0.3	_	8.1	13.2	1.0	15.0	20
	t _{pHL}	—	5.0 ± 0.5	—	6.0	9.7	1.0	11.0	ns
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD}		(Note)	_	29	_	—	—	pF

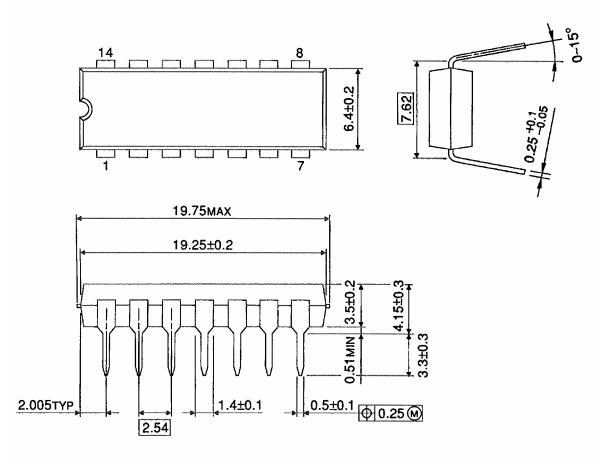
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

DIP14-P-300-2.54

Unit : mm

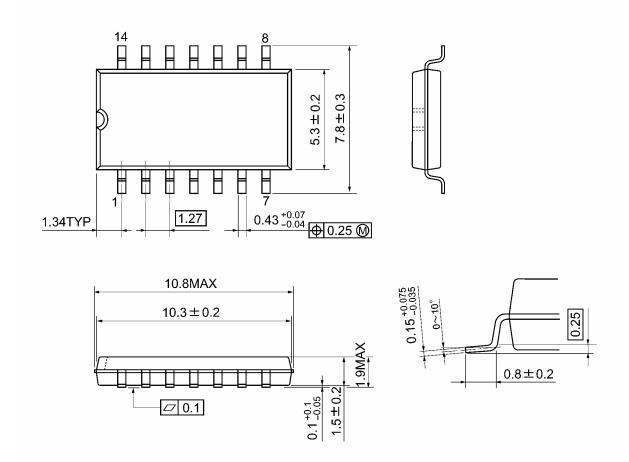


Weight: 0.96 g (typ.)

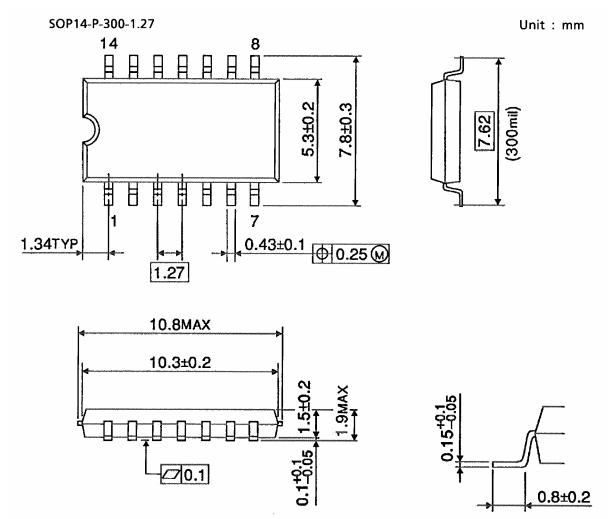


SOP14-P-300-1.27A

Unit: mm

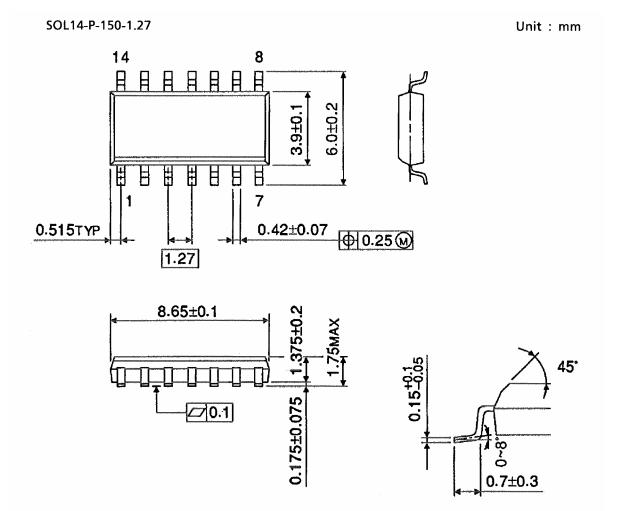


Weight: 0.18 g (typ.)



Weight: 0.18 g (typ.)

Package Dimensions (Note)

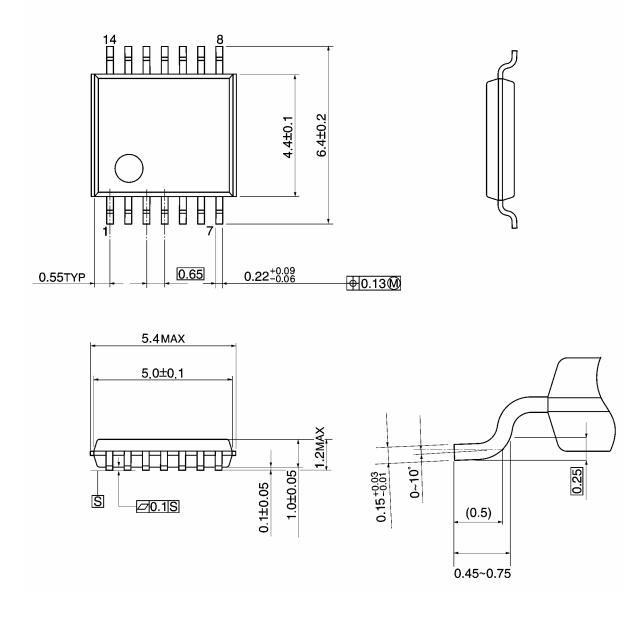


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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20070701-EN

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